

2SC4705

Low-Frequency General-Purpose Amplifier, Applications (High hFE)

Applications

· Low-frequency general-purpose amplifier, drivers, muting circuits.

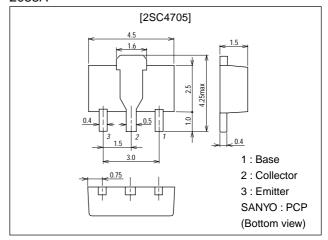
Features

- · High DC current gain (h_{FE}=800 to 3200).
- · Low collector-to-emitter saturation voltage : $V_{CE(sat)} \le 0.5 V$ max.
- · High V_{EBO} : V_{EBO}≥15V.
- · Small size making it easy to provide high-density, hybrid ICs.

Package Dimensions

unit:mm

2038A



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		60	V
Collector-to-Emitter Voltage	VCEO		50	V
Emitter-to-Base Voltage	V _{EBO}		15	V
Collector Current	IC		200	mA
Collector Current (Pulse)	I _{CP}		300	mA
Base Current	Ι _Β		40	mA
Collector Dissipation	PC	Mounted on ceramic board (250mm ² ×0.8mm)	1.3	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

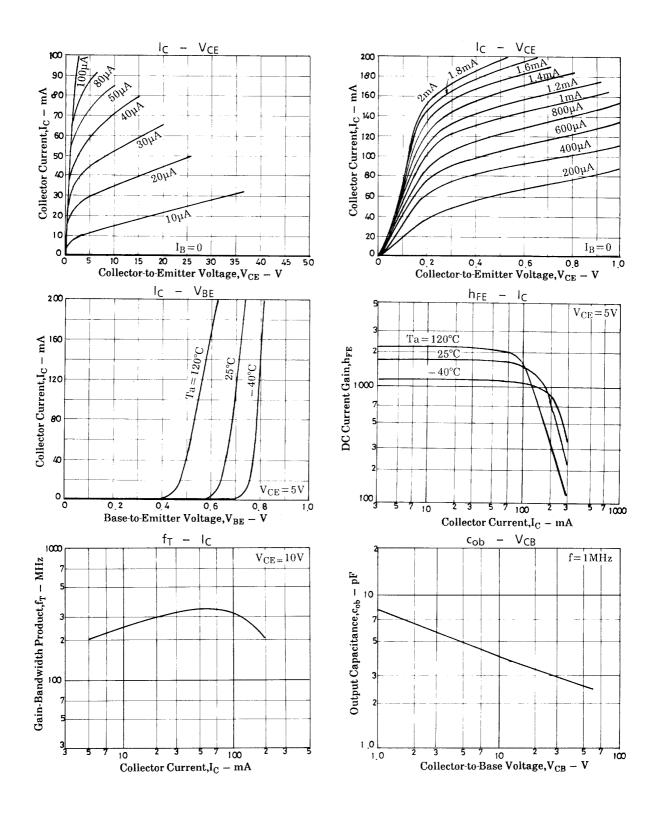
Electrical Characteristics at Ta = 25°C

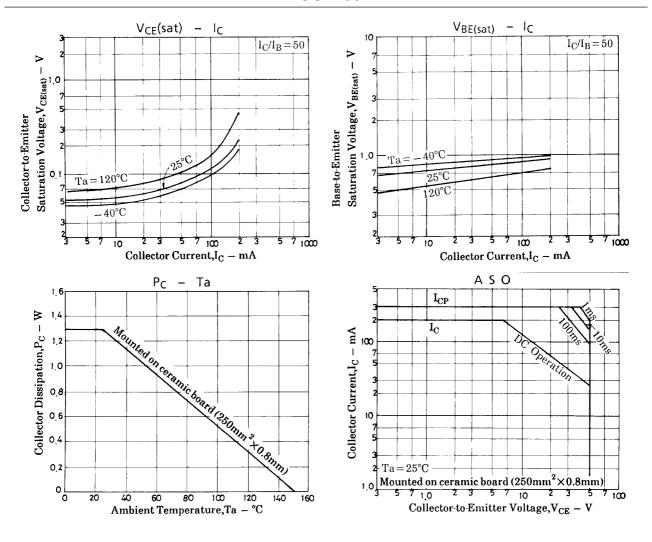
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	J Orlit
Collector Cutoff Current	I _{CBO}	V _{CB} =40V, I _E =0			0.1	μΑ
Emitter Cutoff Current	I _{EBO}	V _{EB} =10V, I _C =0			0.1	μΑ
DC Current Gain	hFE	V _{CE} =5V, I _C =100mA	800	1500	3200	
Gain-Bandwidth Product	fT	V _{CE} =10V, I _C =10mA		250		MHz
Output Capacitance	C _{ob}	V _{CB} =10V, f=1MHz		4.0		pF

Marking :CP

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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Emitter Saturation Voltage	VCE(sat)	I _C =100mA, I _B =2mA		0.12	0.5	V
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =100mA, I _B =2mA		0.85	1.2	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C =10μA, I _E =0	60			V
Collector-to-Emitter Breakdown Voltage	V _(BR) CEO	I _C =1mA, R _{BE} =∞	50			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I _E =10μA, I _C =0	15			V





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